High Voltage EL Lamp Driver

Features

- ▶ 1.8V to 6.5V operating supply voltage
- DC to AC conversion
- Separately adjustable lamp and converter frequency
- Output voltage regulation
- Enable/disable function
- Patented output timing for high efficiency
- <100nA shutdown current</p>
- Split supply capability
- LCD backlighting

Applications

- Portable Transceivers
- Remote Control Units
- Calculators
- PDAs
- Global Positioning Systems (GPS)

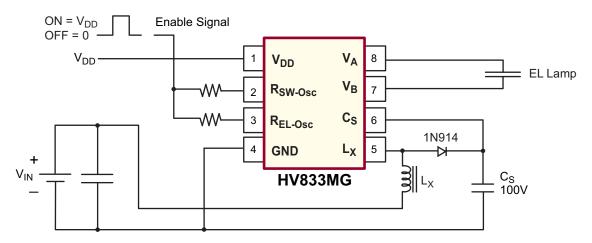
General Description

The Supertex HV833 is a high voltage driver designed for driving EL lamps of up to 35nF (10-12in²). The input supply voltage range is from 1.8V to 6.5V. The device uses a single inductor and a minimum number of passive components. The nominal regulated output voltage that is applied to the EL lamp is ± 90 V. The chip can be enabled/disabled by connecting a resistor between the $R_{\text{SW-Osc}}$ pin and the V_{DD}/GND pins.

The HV833 has two internal oscillators, a switching MOSFET, and a high voltage EL lamp driver. The frequency for the switching MOSFET is set by an external resistor connected between the $R_{\text{SW-Osc}}$ pin and the V_{DD} supply pin. The EL lamp driver frequency is set by an external resistor connected between the $R_{\text{EL-Osc}}$ pin and the V_{DD} pin. An external inductor is connected between the L_{X} pin and V_{DD} or V_{IN} pin. A 0.003-0.1µF capacitor is connected between the C_{S} pin and the GND pin. The EL lamp is connected between the V_{A} pin and the V_{B} pin.

The switching MOSFET charges the external inductor and discharges it into the capacitor at C_s . The voltage at C_s will start to increase. Once the voltage at C_s reaches a nominal value of 90V, the switching MOSFET is turned OFF to conserve power. The outputs V_A and V_B are configured as an H bridge and are switching in opposite states to achieve 180V peak-to-peak across the EL lamp.

Typical Application Circuit



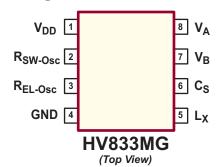
Ordering Information

| Device | Package Options | | | | | | |
|--------|---------------------|-----------|--|--|--|--|--|
| Device | MSOP-8 ¹ | | | | | | |
| HV833 | HV833MG | HV833MG-G | | | | | |

⁻G indicates package is RoHS compliant ('Green')

B

Pin Configuration



Absolute Maximum Ratings

| Parameter | Value |
|---------------------------------|-----------------|
| Supply voltage V _{DD} | -0.5V to 7.5V |
| Output voltage, V _{cs} | -0.5V to 125V |
| Operating Temperature | -40°C to +85°C |
| Storage Temperature | -65°C to +150°C |
| MSOP-8 Power Dissipation | 300mW |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

Recommended Operating Conditions

| Symbol | Parameter | Min | Тур | Max | Units | Conditions |
|-----------------|---|-----|-----|------|-------|------------|
| V_{DD} | Supply voltage | 1.8 | - | 6.5 | V | |
| f _{EL} | V _{A-B} output drive frequency | 60 | - | 1000 | Hz | |
| T _A | Operating Temperature | -25 | - | +85 | °C | |

DC Electrical Characteristics (Over recommended operating conditions unless otherwise specified, T_A=25°C)

| Symbol | Parameter | Min | Тур | Max | Units | Conditions |
|---------------------|--|-----|-----|-----|-------|---|
| R _{DS(ON)} | On-resistance of switching transistor | - | - | 4.0 | Ω | I = 100mA |
| V _{cs} | Max. output regulation voltage | 80 | 90 | 100 | V | V _{DD} = 1.8V to 6.5V |
| V _{A-B} | Max differential output voltage across lamp | 160 | 180 | 200 | V | V _{DD} = 1.8V to 6.5V |
| I _{DDQ} | Quiescent V _{DD} supply current | - | - | 100 | nA | R _{SW-Osc} = Low |
| I _{DD} | Input current going into the V _{DD} pin | - | - | 150 | μA | V _{DD} = 1.8V to 6.5V. See Figure 1. |
| I _{IN} | Input current including inductor current | - | 56 | 64 | mA | V _{IN} = 3.3V. See Figure 1. |
| V _{cs} | Output voltage on V _{cs} | 63 | 72 | 81 | V | V _{IN} = 3.3V. See Figure 1. |
| f _{EL} | V _{DIFF} output drive frequency | 240 | 270 | 300 | Hz | V _{IN} = 3.3V. See Figure 1. |
| F _{sw} | Switching transistor frequency | 55 | 65 | 75 | kHz | V _{IN} = 3.3V. See Figure 1. |
| D | Switching transistor duty cycle | - | 88 | - | % | See Figure 1. |

Enable/Disable Function Table

| Symb | ol Parameter | Min | Тур | Max | Units | Conditions |
|------|--------------------------|-----------------------|-----|-----------------|-------|--------------------------------|
| EN- | Logic input low voltage | 0 | - | 0.5 | V | V _{DD} = 1.8V to 6.5V |
| EN-l | Logic input high voltage | V _{DD} - 0.5 | - | V _{DD} | V | V _{DD} = 1.8V to 6.5V |

Functional Block Diagram

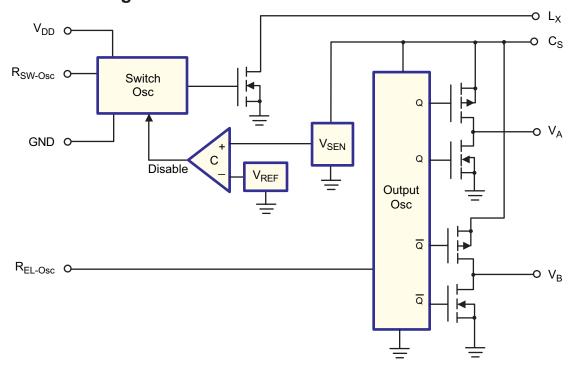
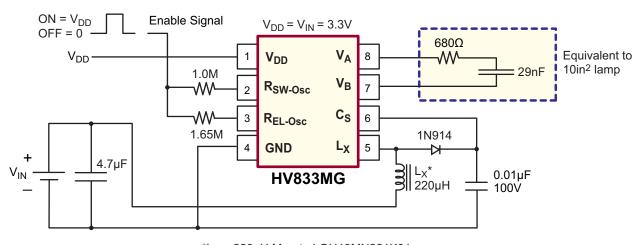


Fig. 1: Typical Application/Test Circuit

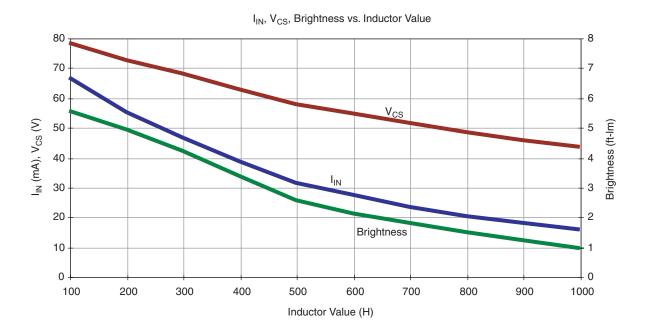


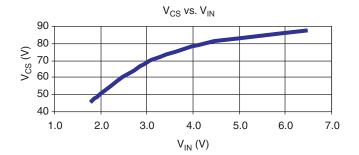
 $L_X = 220\mu$ H Murata LQH43MN221K01

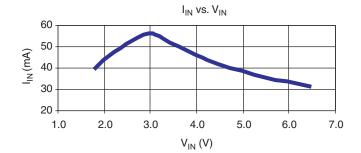
Typical Performance

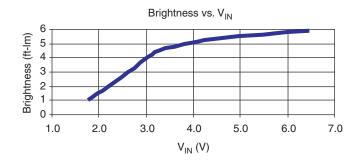
| Device | Lamp Size | V _{IN} | I _{IN} | V _{cs} | f _{EL} | Brightness | T _A |
|---------|-----------|-----------------|-----------------|------------------------|-----------------|------------|-----------------|
| HV833MG | 10in² | 3.3V | 56mA | 72V | 270Hz | 5.0ft-lm | -25°C to + 85°C |

Typical Performance Curves for Fig. 1 (EL Lamp = 10.0in², $V_{IN} = V_{DD}$)









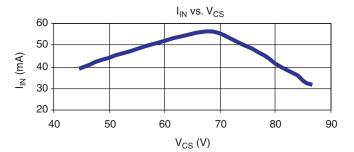
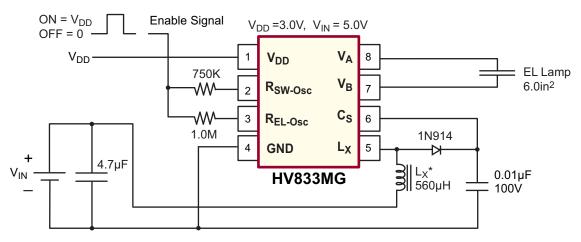


Fig. 2: Typical Application



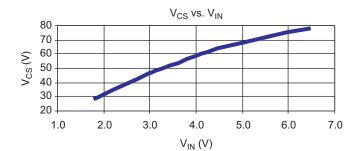
*L_X = 560µH Murata LQH43MN561K01

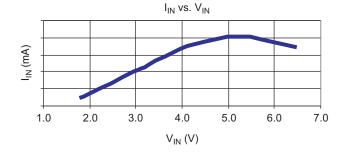
Typical Performance

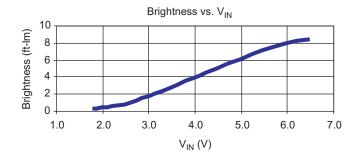
| Device | Lamp Size | V _{IN} | I _{IN} | V _{cs} | f _{EL} | Brightness | T _A |
|---------|--------------------|-----------------|-----------------|-----------------|-----------------|------------|-----------------|
| HV833MG | 6.0in ² | 5.0V | 30mA | 70V | 440Hz | 6.0ft-Im | -25°C to + 85°C |

Typical Performance Curves for Fig. 2 (EL Lamp = 6.0in², V_{DD} = 3.0, V_{IN} = 5.0V)









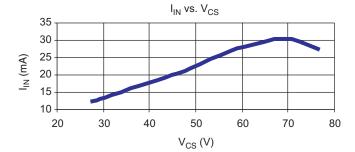
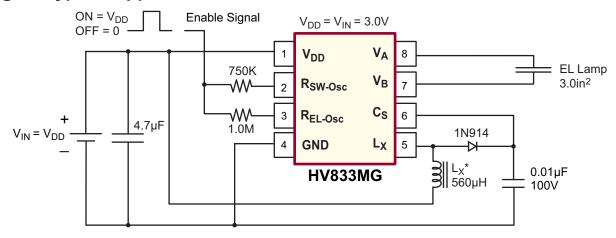


Fig. 3: Typical Application

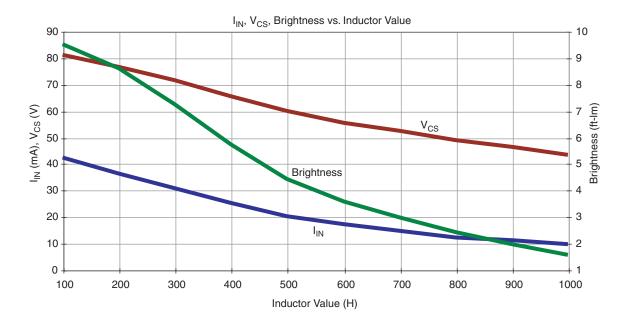


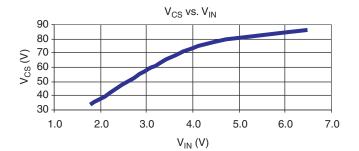
*L_X = 560µH Murata LQH43MN561K01

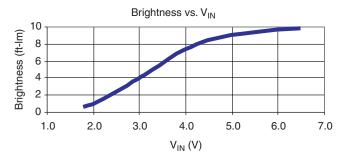
Typical Performance

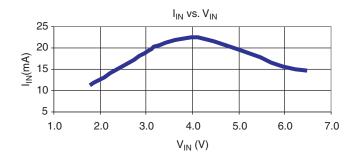
| Device | Lamp Size | V _{IN} | I _{IN} | V _{cs} | f _{EL} | Brightness | T _A |
|---------|--------------------|-----------------|-----------------|-----------------|-----------------|------------|-----------------|
| HV833MG | 3.0in ² | 3.0V | 20mA | 60V | 440Hz | 4.0ft-Im | -25°C to + 85°C |

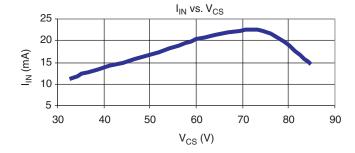
Typical Performance Curves for Fig. 3 (EL Lamp = 3.0in², $V_{IN} = V_{DD}$)











Enable/Disable Configuration

The HV833 can be easily enabled and disabled via a logic control signal on the R_{SW} and R_{EL} resistors as shown in the Typical Application Circuit on the front page. The control signal can be from a microprocessor. R_{SW} and R_{EL} are typically

very high values. Therefore, only 10's of microamperes will be drawn from the logic signal when it is at a logic high (enable) state. When the microprocessor signal is high the device is enabled and when the signal is low, it is disabled.

Enable/Disable Table

| Enable Signal | HV833 |
|-----------------|---------|
| V _{DD} | Enable |
| 0V | Disable |

Split Supply Configuration for Battery Voltages of Higher than 6.5V

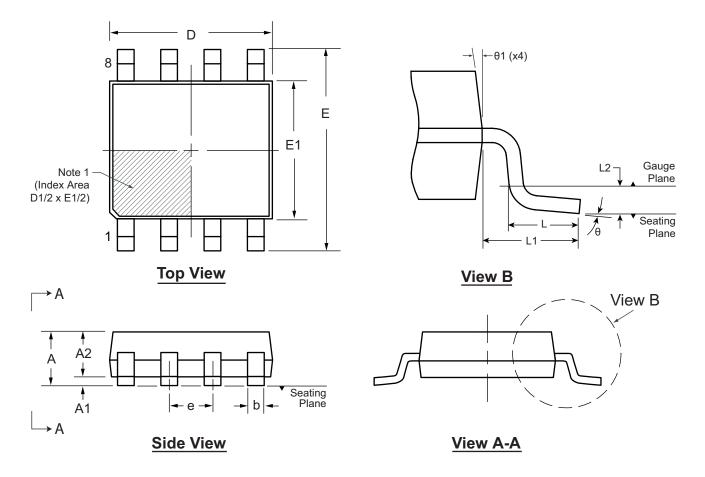
The Typical Application Circuit on the first page can also be used with high battery voltages such as 12V as long as the input voltage, $V_{\rm DD}$, to the HV833 device is within its specifications of 1.8V to 6.5V. Split supply configuration is shown on Fig. 2.

External Component Description

| External Component | Selection Guide Line |
|--------------------------|---|
| Diode | Fast reverse recovery diode, 100V 1N4148 or equivalent. |
| C _s Capacitor | $0.003\mu F$ to $0.1\mu F$, $100V$ capacitor to GND is used to store the energy transferred from the inductor. |
| R _{EL-Osc} | The EL lamp frequency is controlled via an external R_{EL} resistor connected between $R_{\text{EL-Osc}}$ and V_{DD} pins of the device. The lamp frequency increases as R_{EL} decreases. As the EL lamp frequency increases, the amount of current drawn from the battery will increase and the output voltage V_{CS} will decrease. The color of the EL lamp is dependent upon its frequency. |
| R _{sw-Osc} | The switching frequency of the converter is controlled via an external resistor, R_{SW} between $R_{\text{SW-Osc}}$ and V_{DD} pins of the device. The switching frequency increases as R_{SW} decreases. With a given inductor, as the switching frequency increases, the amount of current drawn from the battery will decrease and the output voltage, V_{CS} , will also decrease. |
| L _x Inductor | The inductor L_χ is used to boost the low input voltage by inductive flyback. When the internal switch is on, the inductor is being charged. When the internal switch is off, the charge stored in the inductor will be transferred to the high voltage capacitor C_s . The energy stored in the capacitor is connected to the internal H-bridge, and therefore to the EL lamp. In general, smaller value inductors, which can handle more current, are more suitable to drive larger size lamps. As the inductor value decreases, the switching frequency of the inductor (controlled by R_{sw}) should be increased to avoid saturation. A 220µH Murata (LQH43MN221) inductor with 5.4 Ω series DC resistance is typically recommended. For inductors with the same inductance value but with lower series DC resistance, |
| Lamp | a lower R_{sw} value is needed to prevent high current draw and inductor saturation. As the EL lamp size increases, more current will be drawn from the battery to maintain high voltage across the EL lamp. The input power, $(V_{lN} \times I_{lN})$, will also increase. If the input power is greater than the power dissipation of the package (300mW), an external resistor in series with one side of the lamp is recommended to help reduce the package power dissipation. |

8-Lead MSOP Package Outline (MG)

3x3mm body, 1.10mm height (max), 0.65mm pitch



vote 1: A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier may be either a mold, or an embedded metal or marked feature.

| Symb | ol | Α | A1 | A2 | b | D | Е | E1 | е | L | L1 | L2 | θ | θ1 |
|--------|-----|------|------|------|------|------|------|------|-------------|------|-------------|-------------|------------|-----|
| Dimen- | MIN | 0.75 | 0.00 | 0.75 | 0.22 | 2.80 | 4.65 | 2.80 | 0.05 | 0.40 | 0.05 | 0.05 | 0° | 5° |
| sion | NOM | - | - | 0.85 | - | 3.00 | 4.90 | 3.00 | 0.65 BSC | 0.60 | 0.95 REF | 0.25 BSC | - | - |
| (mm) | MAX | 1.10 | 0.15 | 0.95 | 0.38 | 3.20 | 5.15 | 3.20 | 000 | 0.80 | IXLI | 550 | 8 º | 15° |

JEDEC Registration MO-187, Variation AA, Issue E, Dec. 2004.

Drawings not to scale.

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